

## P-Channel 100 V (D-S) MOSFET

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)	$Q_g$ (Typ.)
- 100	0.043 at $V_{GS} = - 10$ V	- 40	35
	0.050 at $V_{GS} = - 4.5$ V	- 30	

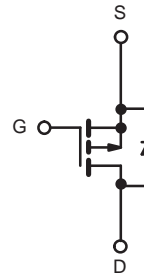
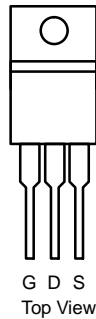
### FEATURES

- DT-Trench Power MOSFET
- 100 %  $R_g$  and UIS Tested

### APPLICATIONS

- Power Switch
- DC/DC Converters
- Portable equipment and battery powered systems


**RoHS**  
 COMPLIANT

**TO-220AB**


P-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS $T_C = 25$ °C, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	- 100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current ( $T_J = 150$ °C)	$I_D$	$T_C = 25$ °C - 40	A
		$T_C = 70$ °C - 35	
Pulsed Drain Current	$I_{DM}$	- 160	
Avalanche Current	$I_{AS}$	- 36	
Single Avalanche Energy <sup>a</sup>	$E_{AS}$	39	mJ
Maximum Power Dissipation <sup>a</sup>	$P_D$	$T_C = 25$ °C 120 <sup>b</sup>	W
		$T_A = 25$ °C <sup>c</sup> 3.8	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	°C

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Limit	Unit
Junction-to-Ambient (PCB Mount) <sup>c</sup>	$R_{thJA}$	50	°C/W
Junction-to-Case (Drain)	$R_{thJC}$	2.2	

Notes:

 a. Duty cycle  $\leq 1$  %.

b. See SOA curve for voltage derating.

c. When Mounted on 1" square PCB (FR-4 material).

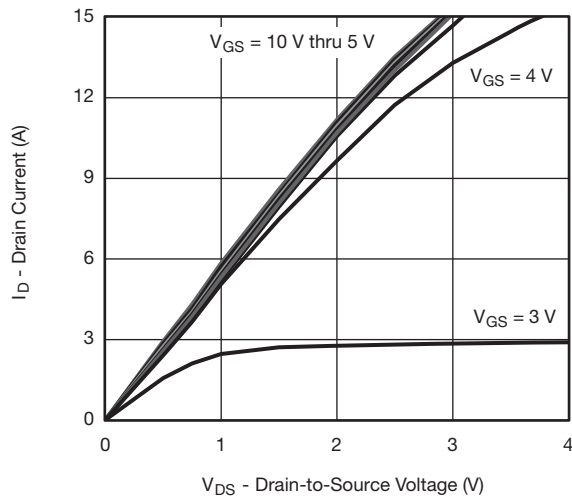
SPECIFICATIONS T <sub>J</sub> = 25 °C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>DS</sub> = 0 V, I <sub>D</sub> = - 250 μA	- 100			V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = - 250 μA	- 1		- 3.5	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V			± 250	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 80 V, V <sub>GS</sub> = 0 V			- 1	μA
		V <sub>DS</sub> = - 80 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C			- 50	
		V <sub>DS</sub> = - 80 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 150 °C			- 250	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> ≤ - 10 V, V <sub>GS</sub> = - 10 V	- 160			A
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 5 A		0.043	0.051	Ω
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 3 A		0.050	0.065	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 5 A		17		S
Dynamic <sup>b</sup>						
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = - 50 V, f = 1 MHz		8510		pF
Output Capacitance	C <sub>oss</sub>			1405		
Reverse Transfer Capacitance	C <sub>rss</sub>			504		
Total Gate Charge <sup>c</sup>	Q <sub>g</sub>	V <sub>DS</sub> = - 50 V, V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 5 A		35		nC
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>DS</sub> = - 50 V, V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 3 A		15		
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			8		
				6		
Gate Resistance	R <sub>g</sub>	f = 1 MHz	1.2	5.7	11.5	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>	V <sub>DD</sub> = - 50 V, R <sub>L</sub> = 17.2 Ω I <sub>D</sub> ≅ - 2.9 A, V <sub>GEN</sub> = - 10 V, R <sub>g</sub> = 1 Ω		18		ns
Rise Time <sup>c</sup>	t <sub>r</sub>			22		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			49		
Fall Time <sup>c</sup>	t <sub>f</sub>			13.5		
Drain-Source Body Diode Ratings and Characteristics T <sub>C</sub> = 25 °C <sup>b</sup>						
Continuous Current	I <sub>S</sub>				- 40	A
Pulsed Current	I <sub>SM</sub>				-160	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = - 2.9 A, V <sub>GS</sub> = 0 V		- 0.7	- 1.5	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 2.9 A, dI/dt = 100 A/μs		50		ns
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>			- 4	- 6	A
Reverse Recovery Charge	Q <sub>rr</sub>				98	147

Notes:

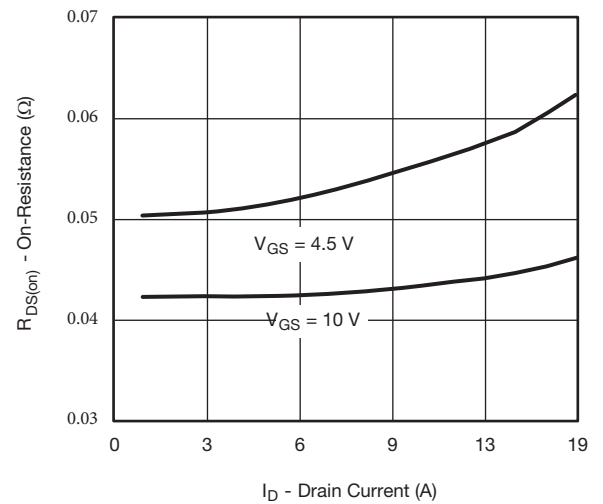
- Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

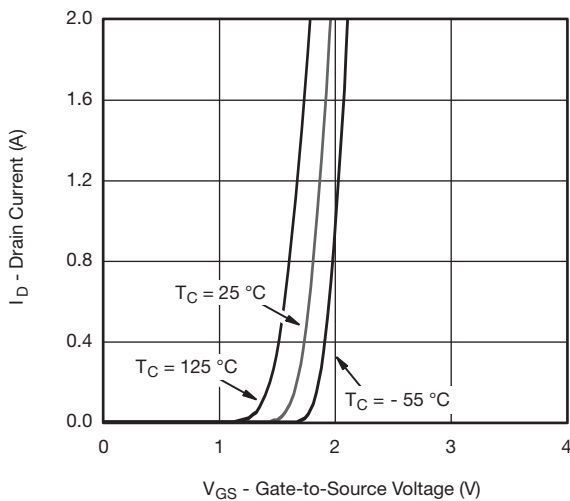
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



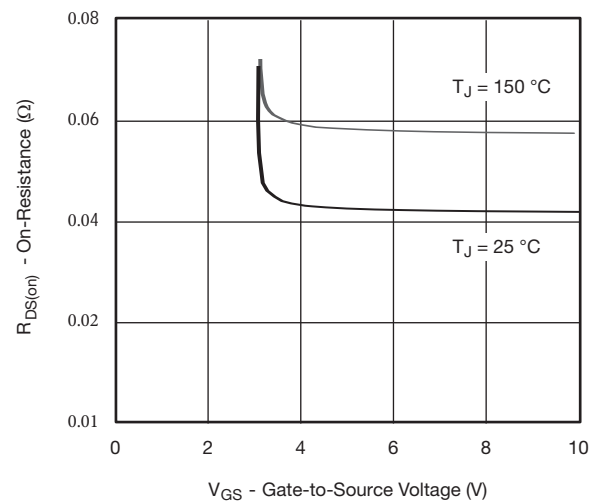
**Output Characteristics**



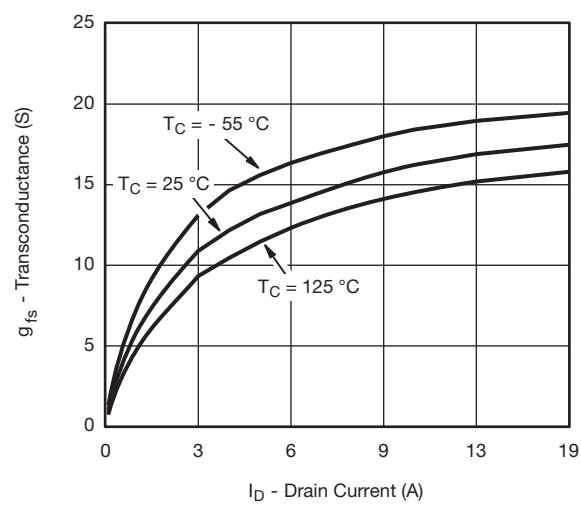
**On-Resistance vs. Drain Current**



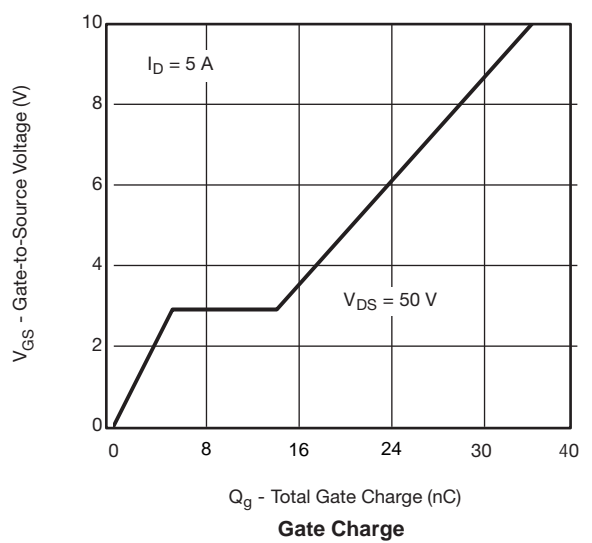
**Transfer Characteristics**



**On-Resistance vs. Gate-to-Source Voltage**

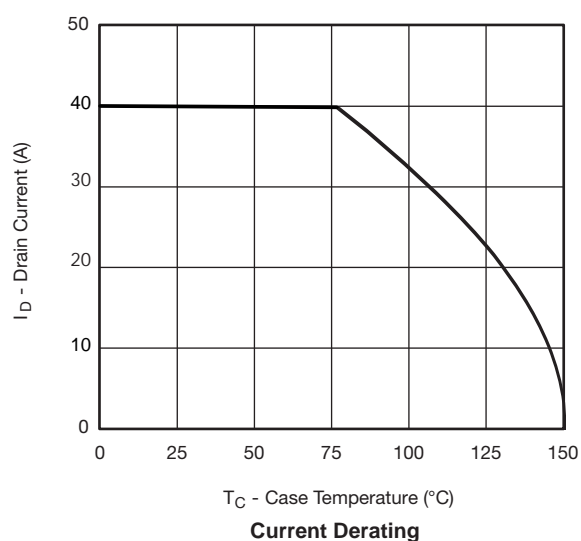
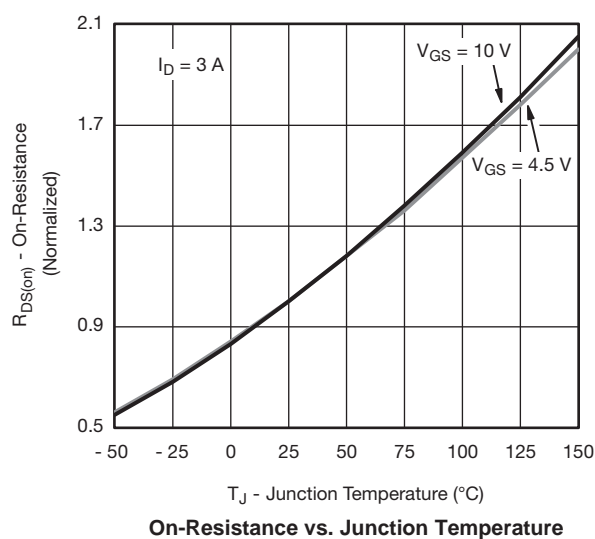
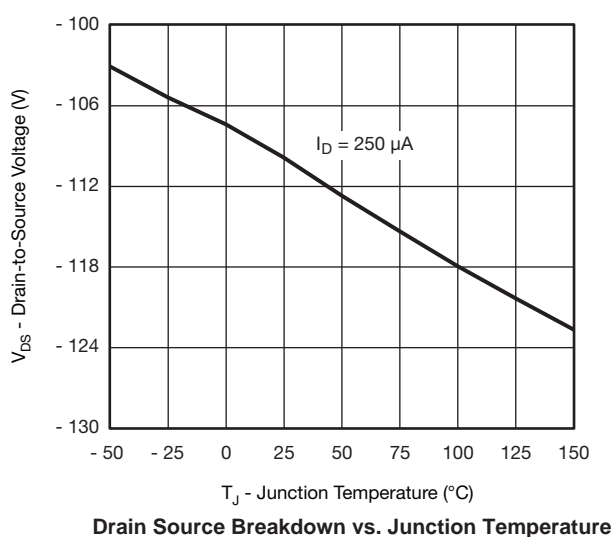
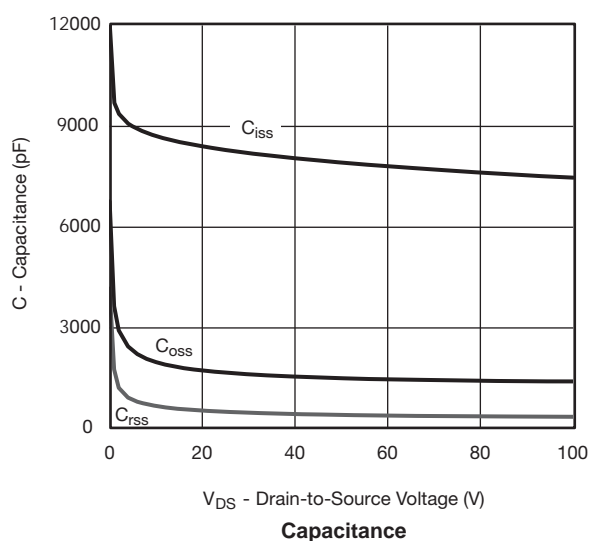
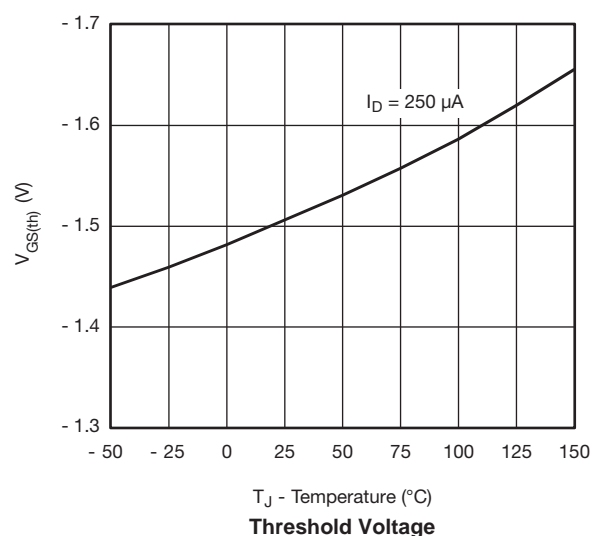
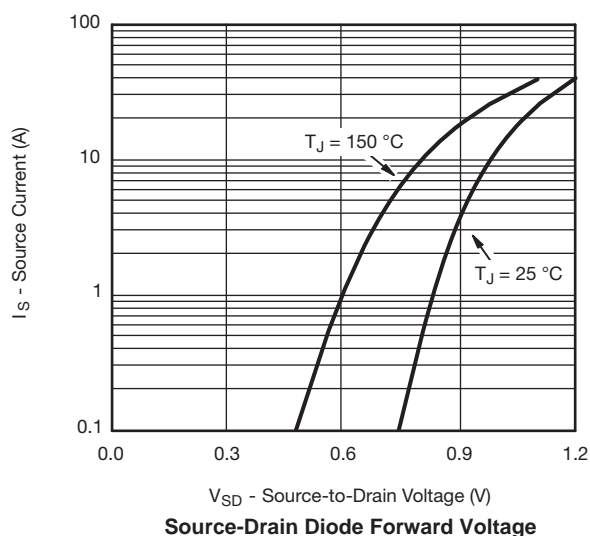


**Transconductance**

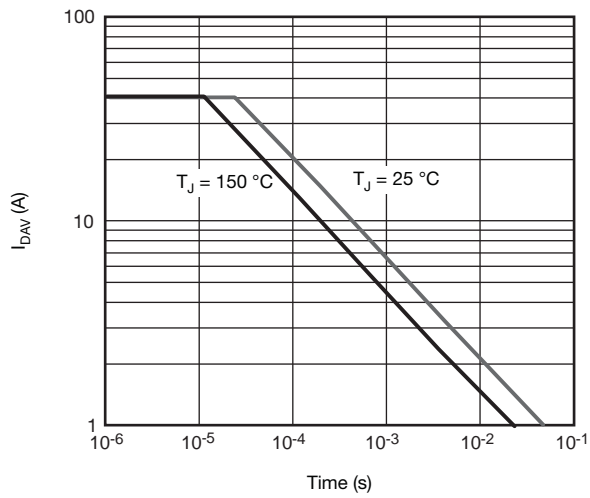


**Gate Charge**

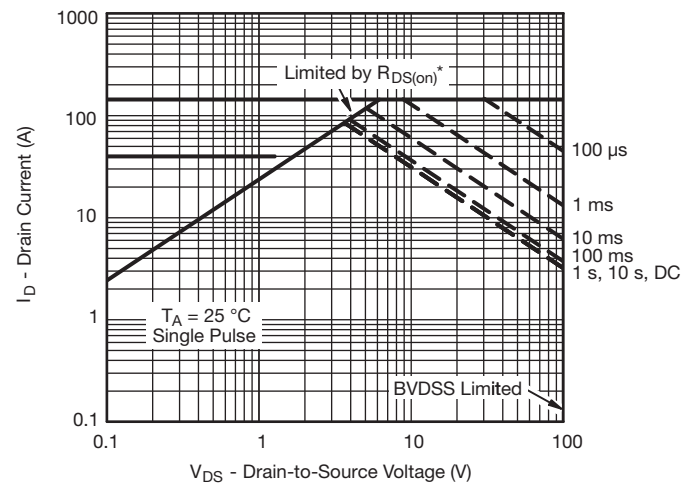
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**Single Pulse Avalanche Current Capability vs. Time**



\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

**Safe Operating Area**

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